

## MiniSKiiP<sup>®</sup> 3

3-phase Converter – Inverter (CI)

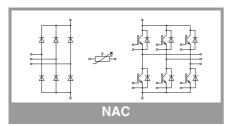
#### SKiiP 37NAC12T4V1

#### Features\*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

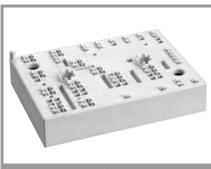
#### Remarks

- Max. case temperature limited to  $T_C=125^{\circ}C$
- Product reliability results valid for  $T_j \le 150^{\circ}C$  (recommended  $T_{j,op} = -40...+150^{\circ}C$ )
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information



Absolut	e Maximum Ratings	6		
Symbol	Conditions		Values	Unit
Inverter	- IGBT			
V <sub>CES</sub>	T <sub>j</sub> = 25 °C		1200	V
lc	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C	90	A
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	73	A
l <sub>C</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C	106	Α
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	86	A
I <sub>Cnom</sub>			75	А
I <sub>CRM</sub>			225	А
V <sub>GES</sub>			-20 20	V
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 150 °C	10	μs
Tj			-40 175	°C
Inverse -	Diode			
V <sub>RRM</sub>	T <sub>i</sub> = 25 °C		1200	V
IF	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C	83	Α
	$T_j = 175 \ ^\circ C$	T <sub>s</sub> = 70 °C	66	Α
l <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C	95	Α
·	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	76	Α
I <sub>FRM</sub>			225	Α
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°, T <sub>i</sub> = 150 °C		430	Α
Tj			-40 175	°C
Rectifier	- Diode			
V <sub>RRM</sub>	T <sub>j</sub> = 25 °C		1600	V
l <sub>F</sub>	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C	81	А
	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 70 °C	60	Α
l <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C	92	А
	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 70 °C	68	А
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	700	Α
	sin 180°	T <sub>j</sub> = 150 °C	490	Α
i²t	t <sub>p</sub> = 10 ms sin 180°	T <sub>j</sub> = 25 °C	2450	A <sup>2</sup> s
		T <sub>j</sub> = 150 °C	1200	A <sup>2</sup> s
Tj			-40 150	°C
Module				•
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20 A per spring		80	
T <sub>stg</sub>	module without TIM		-40 125	
	AC sinus 50 Hz, 1 min		2500	V

Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
V <sub>CE(sat)</sub>	I <sub>C</sub> = 75 A V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 25 °C		1.85	2.10	V
		T <sub>j</sub> = 150 °C		2.25	2.45	V
V <sub>CE0</sub>	chiplevel	T <sub>j</sub> = 25 °C		0.80	0.90	V
		T <sub>j</sub> = 150 °C		0.70	0.80	V
r <sub>CE</sub>	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 25 °C		14	16	mΩ
		T <sub>j</sub> = 150 °C		21	22	mΩ
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_C = 3 \text{ mA}$		5	5.8	6.5	V
I <sub>CES</sub>	$V_{GE}$ = 0 V, $V_{CE}$ = 1200 V, $T_j$ = 25 °C				1	mA



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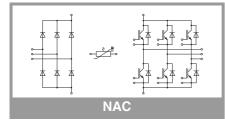
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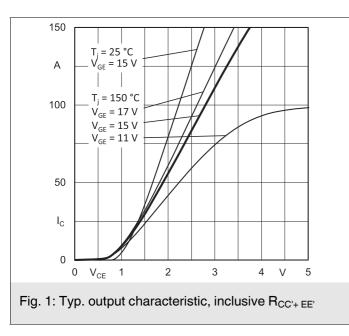
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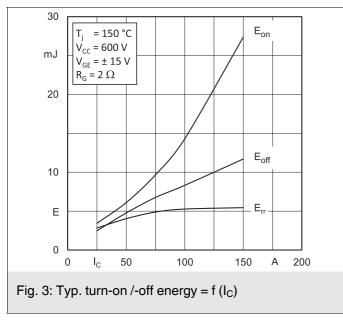
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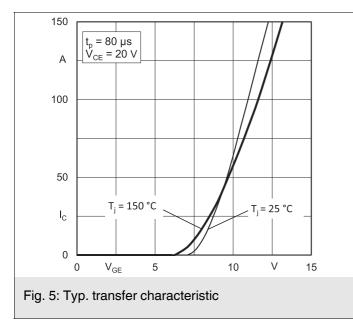
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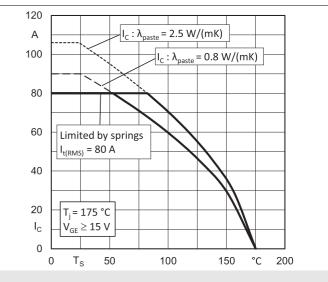
Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Uni
Inverter -	IGBT					
Cies		f = 1 MHz		4.40		nF
Coes	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	f = 1 MHz		0.29		nF
C <sub>res</sub>		f = 1 MHz	0.24		nF	
Q <sub>G</sub>	V <sub>GE</sub> = - 8 V+ 15 V			425		nC
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			10		Ω
t <sub>d(on)</sub>	V <sub>CC</sub> = 600 V	T <sub>j</sub> = 150 °C		150		ns
t <sub>r</sub>	l <sub>C</sub> = 75 A	T <sub>j</sub> = 150 °C	32		ns	
Eon	$R_{G \text{ on}} = 2 \Omega$ $R_{G \text{ off}} = 2 \Omega$	T <sub>j</sub> = 150 °C	9.7			m
t <sub>d(off)</sub>	$h_{G off} = 2.32$ di/dt <sub>on</sub> = 2400 A/µs	T <sub>j</sub> = 150 °C	355			ns
t <sub>f</sub>	di/dt <sub>off</sub> = 355 A/µs	T <sub>j</sub> = 150 °C	60			ns
E <sub>off</sub>	V <sub>GE</sub> = +15/-15 V	T <sub>j</sub> = 150 °C	6.8			m
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =0.8	3 W/(mK)	0.58			K/V
R <sub>th(j-s)</sub>	per IGBT, $\lambda_{paste}=2.5$	5 W/(mK)		0.44		K/V
Inverse -	Diode					
$V_F = V_{EC}$	I <sub>F</sub> = 75 A	T <sub>j</sub> = 25 °C		2.17	2.49	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 150 °C		2.11	2.42	v
V <sub>F0</sub>	chipievei	T <sub>i</sub> = 25 °C		1.30	1.50	v
V F0	- chiplevel	$T_i = 150 \text{ °C}$		0.90	1.10	V
r <sub>F</sub>	chiplevel	$T_i = 25 °C$		12	13	m
••		$T_i = 150 ^{\circ}C$		16	18	m
I <sub>RRM</sub>	I <sub>F</sub> = 75 A	$T_i = 150 ^{\circ}C$		62		A
Q <sub>rr</sub>	V <sub>GE</sub> = -15 V	$T_i = 150 ^{\circ}C$		12.6		μΟ
Err	$-V_{CC} = 600 V$	,		4.9		m
_	$di/dt_{off} = 1940 \text{ A/}\mu\text{s}$					K/V
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}=0$ .			0.75		K/V
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}=2$ .	5 W/(IIIK)		0.61		r./ v
Rectifier ·				1.00	1.01	
$V_F = V_{EC}$	$I_F = 25 A$	T <sub>j</sub> = 25 °C		1.00	1.21	V
	chiplevel	T <sub>j</sub> = 125 °C		0.90	1.10	V
V <sub>F0</sub>	chiplevel	$T_j = 25 °C$		0.88	0.98	V
		T <sub>j</sub> = 125 °C		0.73	0.83	V
r <sub>F</sub>	chiplevel	$T_j = 25 \ ^{\circ}C$		4.8	9.2	m
<b>D</b>	ner Diede ) 0	$T_{j} = 125 \text{ °C}$		6.8	11	m
R <sub>th(j-s)</sub>	per Diode, $\lambda_{paste}$ =0.8 W/(mK) per Diode, $\lambda_{paste}$ =2.5 W/(mK)			0.9		K/V
R <sub>th(j-s)</sub>	per Diode, Apaste=2.	5 W/(IIIK)		0.75		K/V
Module	1	I			0-	1
Ms	to heat sink		2		2.5	Nn
W				82		g
Temperat	ture Sensor					
R <sub>100</sub>	T <sub>r</sub> =100°C (R <sub>25</sub> =1000Ω)			1670 ± 3%		Ω
R <sub>(T)</sub>	$R_{(T)}$ =1000Ω[1+A(T- , A = 7.635*10 <sup>-3</sup> °C <sup>-1</sup> B = 1.731*10 <sup>-5</sup> °C <sup>-2</sup>					

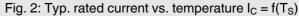


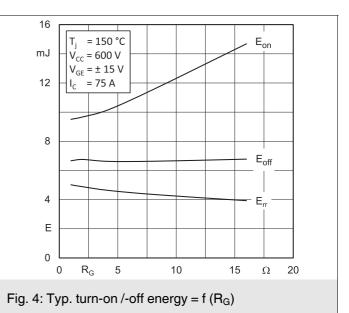


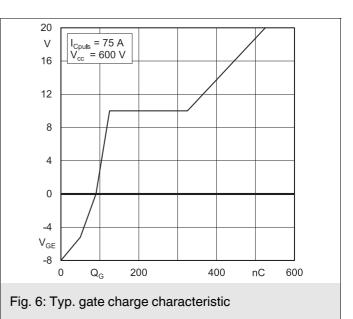




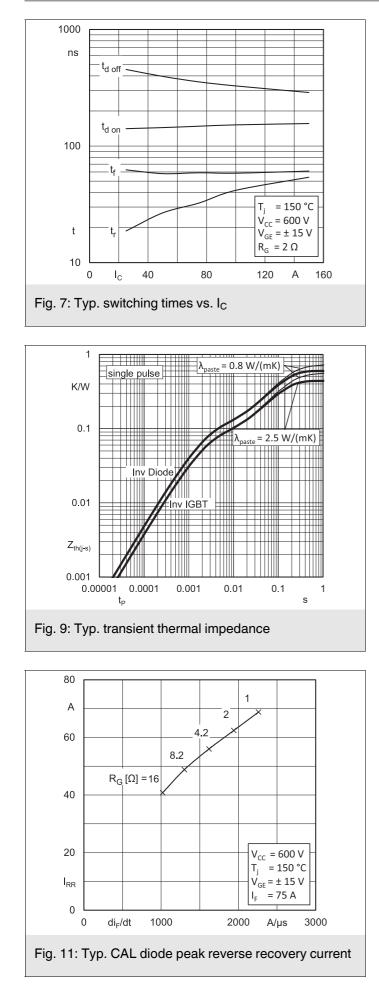


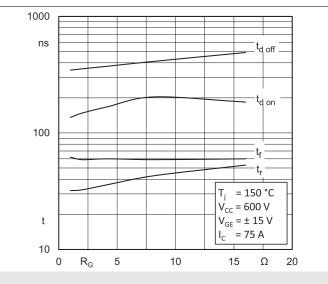


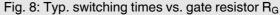


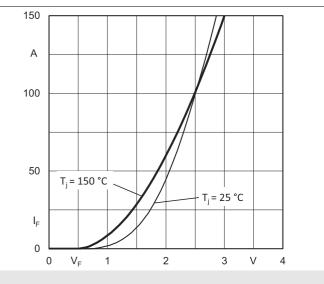


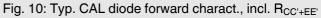
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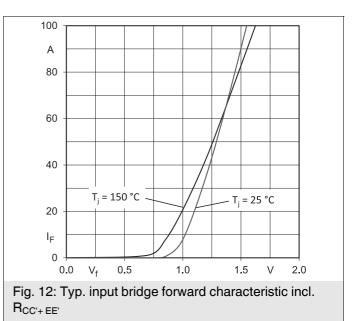








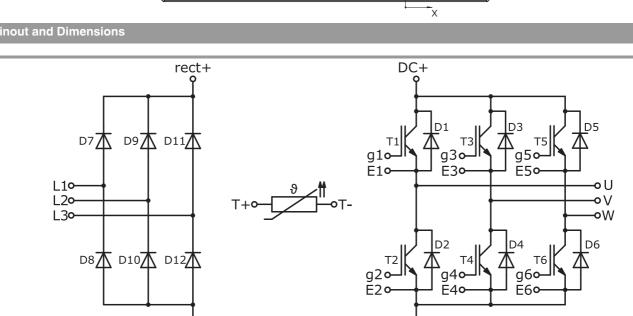




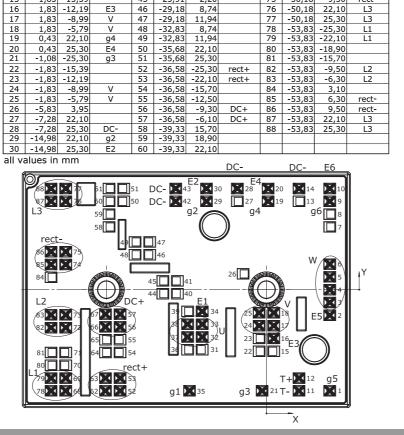
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**Pinout** 

DČ-



**Pinout and Dimensions** 



Pin out

Function

U

U

E1

g1

U

U

DC-

DC

X Y -16,05 -15,02

-16,05 -11,82

33 -16,05 -8,62

34 -16,05 -5,42 35 -19,23 -25,30

36 -19,70 -15,02

37-19,70-11,8238-19,70-8,6239-19,70-5,42

40-22,26-1,0041-22,262,2042-22,6822,10

25,30

-1,00 2,20

43 -22,68 44 -25,91 45 -25,91

Pin X 61 -39,33

66 -40,23

73 -50,18 74 -50,18 75 -50,18

76

77

64

65

62 -40,23 -25,30

63 -40,23 -22,10

67-40,23-6,1068-50,18-25,3069-50,18-22,10

70-50,18-18,9071-50,18-15,7072-50,18-9,50

-40,23 -15,70 -40,23 -12,50

Function

rect+

rect+

DC+

DC+

L1

L1

L2

L2

rect-

rect-

L3

L3

25,30

-9,30

-6,30

6,30 9,50

Function Pin g5 31

32

g5 E5

W

w

Ŵ

W

g6

E6

T+

DC

E3

V

٧

30	-14,98	25,30
all va	alues in	mm

ç

rect-

# SKiiP 37NAC12T4V1

Pin

1 2 3

4 5

6

7 8 9

10

11 12

13

14

15

16

17

X Y 15,83 -25,30

-6,40

-3,20

6,40

15,70

18,90 22,10

0 3,20

15,83

15,83

15,83 15,83

15,83

15,83

15,83 15,83

15,83 15,83 25,30 8,13 -25,30

1,83

8,13 -22,10

8,13 22,10 8,13 25,30 1,83 -15,39

1,83 -12,19

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

#### **\*IMPORTANT INFORMATION AND WARNINGS**

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